

Vishay Siliconix

1.2 A Slew Rate Controlled Load Switch

DESCRIPTION

The SiP4282 series is a slew rate controlled high side switch. The switch is of a low on resistance p-channel MOSFET that supports continuous current up to 1.2 A.

The SiP4282 series operates with an input voltage from 1.8 V to 5.5 V. It offers under voltage lock out that turns the switch off when an input under voltage condition exists. The "A" option without UVLO extends the minimum operation voltage from 1.8 V down to 1.5 V. The SiP4282 is available in two different versions of slew rates, 100 μ s and 1 ms. The SiP4282 series integrates load discharge circuit to ensure the discharge of capacitive load when the switch is disabled.

The SiP4282 features low input logic level to interface with low control voltage from microprocessors. This device has a very low operating current (typically 2.5 μ A for SiP4282 and 50 pA for SiP4282A).

The SiP4282 is available in lead (Pb)-free package options including 6 pin PowerPAK[®] SC-75-6, and 4 pin TDFN4 1.2 mm x 1.6 mm DFN4 packages. The operation temperature range is specified from -40 °C to +85 °C.

The SiP4282 compact package options, operation voltage range, and low operating current make it a good fit for battery power applications.

FEATURES

- 1.8 V to 5.5 V input voltage range for SiP4282
- 1.5 V to 5.5 V input voltage range for SiP4282A
- Very low R_{DS(on)}, typically 105 mW at 5 V and CO 175 mW at 3 V
- Slew rate controlled turn-on time options: 100 μs and 1 ms
- Fast shutdown load discharge
- Low quiescent current, 4 µA for SiP4282
- Low quiescent current, 1 µA for SiP4282A
- Low shutdown current < 1 μA
- UVLO of 1.4 V for SiP4282
- PowerPAK SC-75 1.6 mm x 1.6 mm and TDFN4 1.2 mm x 1.6 mm packages
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Cellular telephones
- Digital still cameras
- Personal digital assistants (PDA)
- Hot swap supplies
- Notebook computers
- Personal communication devices
- Portable Instruments



Fig. 1 - SiP4282 Typical Application Circuit

ORDERING INFORMATION									
TEMPERATURE RANGE	PACKAGE	SLEW RATE (TYP.)	UNDER VOLTAGE LOCKOUT	MARKING	PART NUMBER				
-40 °C to +85 °C	PowerPAK SC-75-6	100 µs	No	LExxx	SiP4282ADVP3-T1GE3				
		100 µs	Yes	LFxxx	SiP4282DVP3-T1GE3				
	TDFN4 1.2 x 1.6	100 µs	No	Bx	SiP4282ADNP3-T1GE4				
		100 µs	Yes	Cx	SiP4282DNP3-T1GE4				

Note

• xxx = lot code

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1 For technical questions, contact: <u>powerictechsupport@vishay.com</u> Document Number: 65740

/ and RoHS COMPLIANT HALOGEN FREE

TYPICAL APPLICATION CIRCUIT



ABSOLUTE MAXIMUM RATINGS								
PARAMETER	LIMIT	UNIT						
Supply input voltage (V _{IN})		-0.3 to 6						
Enable input voltage (V _{ON / OFF})		-0.3 to 6	V					
Output voltage (V _{OUT})		-0.3 to V _{IN} + 0.3						
Maximum continuous switch current (I _{max.})	1.4							
Maximum pulsed current (I _{DM}) V _{IN}	$V_{IN} \ge 2.5 V$	3	А					
	V _{IN} < 2.5 V	1.6						
ESD rating (HBM)		4000	V					
Junction temperature (T _J)		-40 to +125	°C					
Thermal resistance $(\theta_{n})^{a}$	6 pin PPAK SC75 ^b	90	°C (M)					
Thermai resistance (OJA) ~	4 pin TDFN4 1.2 mm x 1.6 mm ^c	170	C/ W					
Power fissingtion $(P_{-})^{a}$	6 pin PPAK SC75 ^b	610	m\\/					
rower inscipation (rD) ~	4 pin TDFN4 1.2 mm x 1.6 mm ^c	324	11174					

Notes

• Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

a. Device mounted with all leads and power pad soldered or welded to PC board

b. Derate 11.1 mW/°C above $T_A = 70$ °C

c. Derate 5.9 mW/°C above $T_A = 70$ °C, see PCB layout

RECOMMENDED OPERATING RANGE							
PARAMETER	LIMIT	UNIT					
Input voltage range (VIN) for SiP4282 version	1.8 to 5.5	V					
Input voltage range (VIN) for SiP4282A version	1.5 to 5.5	V					
Operating temperature range	-40 to +85	°C					

SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	LIMITS -40 °C to +85 °C			UNIT			
		$V_{IN} = 5$, $I_A = -40$ °C to +85 °C (typical values are at $T_A = 25$ °C)	MIN. ^a	TYP. ^b	MAX. ^a				
Operating voltage ^c	Mari	For SiP4282xxx	1.8	-	5.5				
Operating voltage	VIN	For SiP4282Axxx	1.5	-	5.5	V			
Under voltage lockout	V _{UVLO}	For SiP4282xxx, V _{IN} falling	1	1.4	1.8				
Under voltage lockout hysteresis	V _{UVLO(hyh)}	For SiP4282xxx	-	250	-	mV			
Quiescent current	Ι _Q	For SiP4282xxx, on / off = active	-	2.5	4				
		For SiP4282Axxx, on / off = active	-	0.00005	1	μΑ			
	R _{DS(on)}	V_{IN} = 5 V, I_L = 500 mA, T_A = 25 °C	-	105	230	mΩ			
		V_{IN} = 4.2 V, I_L = 500 mA, T_A = 25 °C	-	110	250				
On-resistance		V_{IN} = 3 V, I_L = 500 mA, T_A = 25 °C	-	135	290				
		V_{IN} = 1.8 V, I_L = 500 mA, T_A = 25 °C	-	230	480				
		For SiP4282Axxx, V_{IN} = 1.5 V, I _L = 500 mA, T _A = 25 °C	-	350	520				
On-resistance temp. coefficient	TC _{RDS}		-	2800	-	ppm/°C			
		For SiP4282Axxx, $V_{IN} \ge 1.5 \text{ V to} < 1.8 \text{ V}$	-	-	0.3	0.3 0.4 V 0.6			
On / off input low voltage ^d	V _{IL}	$V_{IN} \ge 1.8 \text{ V to} < 2.7 \text{ V}$	-	-	0.4				
		$V_{IN} \geq 2.7 \ V \ to \leq 5.5 \ V$	-	-	0.6				

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SPECIFICATIONS

SPECIFICATIONS									
PABAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	LIMITS -40 °C to +85 °C			UNIT			
	0111201	$V_{IN} = 5$, $T_A = -40$ °C to +85 °C (typical values are at $T_A = 25$ °C)	MIN. ^a	TYP. ^b	MAX. ^a	•••••			
		$V_{\text{IN}} \geq 1.5$ V to < 2.7 V	1.3	-	-				
On / off input high voltage ^d	V _{IH}	$V_{IN} \geq 2.7 \text{ V}$ to $< 4.2 \text{ V}$	1.5	-	-	V			
		$V_{IN} \geq 4.2 \ V$ to $\leq 5.5 \ V$	1.8	-	-				
On / off input leakage	I _{SINK}	$V_{On / off} = 5.5 V$	-	-	1	μA			
Output pulldown resistance	R _{PD}	On / off = Inactive, $T_A = 25 \ ^{\circ}C$	-	180	250	Ω			
SiP4282xxx3 and SiP4282Axxx3 Ver	sions								
Output turn-on delay time	t _{d(on)}	V_{IN} = 5 V, R_{LOAD} = 10 Ω , T_A = 25 °C	-	20	40				
Output turn-on rise time	t _(on)	V_{IN} = 5 V, R_{LOAD} = 10 Ω , T_A = 25 °C	-	140	180	μs			
Output turn-off delay time	t _{d(off)}	V_{IN} = 5 V, R_{LOAD} = 10 Ω , T_A = 25 °C	-	4	10				

Notes

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum

b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

c. Part requires minimum start-up of $V_{\text{IN}} \geq 2$ V to ensure operation down to 1.8 V

d. For V_{IN} outside this range consult typical on / off threshold curve

PIN CONFIGURATION



Fig. 2 - PPAK SC75-6 Package



Fig. 3 - TDFN4 1.2 mm x 1.6 mm Package

PIN DESCRIPTION								
			FUNCTION					
PPAK	TDFN4	INAME	FUNCTION					
1, 2	3	IN	This pin is the p-channel MOSFET source connection. Bypass to ground through a 1 μF capacitor					
3	2	GND	Ground connection					
4	4	ON/OFF	Enable input					
5, 6	1	OUT	This pin is the p-channel MOSFET drain connection. Bypass to ground through a 0.1 μ F capacitor					



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)



Fig. 4 - Quiescent Current vs. Input Voltage



Fig. 5 - Quiescent Current vs. Input Voltage



Fig. 6 - Quiescent Current vs. Temperature



Fig. 7 - Quiescent Current vs. Temperature







Fig. 9 - Off Switch Current vs. Temperature

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)



Fig. 10 - R_{DS(on)} vs. Input Voltage







Fig. 12 - Output Pull-Down Resistance vs. Temperature



Fig. 13 - On / Off Threshold vs. Input Voltage



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TYPICAL WAVEFORMS



SiP4282xxx3 and SiP4282Axxx3 Switching ($V_{IN} = 3 V$)



SiP4282xxx3 and SiP4282Axxx3 Turn-Off ($V_{IN} = 3 V$)



SiP4282xxx3 and SiP4282Axxx3 Switching (V $_{\rm IN}$ = 5 V)





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BLOCK DIAGRAM



Fig. 14 - SiP4282 Functional Block Diagram

PCB LAYOUT



Fig. 15 - TDFN4 1.2 mm x 1.6 mm PCB Layout



DETAILED DESCRIPTION

The SiP4282 is a p-channel MOSFET power switches designed for high-side slew rate controlled load-switching applications. Once turned on, the slew-rate control circuitry is activated and current is ramped in a linear fashion until it reaches the level required for the output load condition. This is accomplished by first elevating the gate voltage of the MOSFET up to its threshold voltage and then by linearly increasing the gate voltage until the MOSFET becomes fully enhanced. At this point, the gate voltage is then quickly increased to the full input voltage to reduce R_{DS(on)} of the MOSFET switch and minimize any associated power losses.

All versions features a shutdown output discharge circuit which is activated at shutdown (when the part is disabled through the on / off pin) and discharges the output pin through a small internal resistor hence, turning off the load. For SiP4282-3, in instances where the input voltage falls below 1.4 V (typically) the under voltage lock-out circuitry protects the MOSFET switch from entering the saturation region or operation by shutting down the chip.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, a 1 μ F or larger capacitor for C_{IN} is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the SiP4282 to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 μ F capacitor or larger across V_{OUT} and GND is recommended to insure proper slew operation. C_{OUT} may be increased without limit to accommodate any load transient condition with only minimal affect on the SiP4282 turn on slew rate time. There are no ESR or capacitor type requirement.

Enable

The on / off pin is compatible with both TTL and CMOS logic voltage levels.

Protection Against Reverse Voltage Condition

The p-channel MOSFET pass transistor has an intrinsic diode that is reversed biased when the input voltage is greater than the output voltage. Should V_{OUT} exceed V_{IN} , this intrinsic diode will become forward biased and allow excessive current to flow into the IC thru the V_{OUT} pin and potentially damage the IC device. Therefore extreme care should be taken to prevent V_{OUT} from exceeding V_{IN} .

In conditions where V_{OUT} exceeds V_{IN} a Schottky diode in parallel with the internal intrinsic diode is recommended to protect the SiP4282.

Thermal Considerations

The SiP4282 is designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A, as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 90 °C/W) the power pad of the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T_J (max.) = 125 °C, the junction-to-ambient thermal resistance for the SC-75 PPAK package, $\theta_{J-A} = 90$ °C/W, and the ambient temperature, T_A , which may be formulaically expressed as:

P (max.) =
$$\frac{T_J (max.) - T_A}{\theta_{J-A}} = \frac{125 - T_A}{90}$$

It then follows that, assuming an ambient temperature of 70 $^{\circ}$ C, the maximum power dissipation will be limited to about 610 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(on)}$ at the ambient temperature.

As an example let us calculate the worst case maximum load current at T_A = 70 °C. The worst case $R_{DS(on)}$ at 25 °C occurs at an input voltage of 1.8 V and is equal to 480 m Ω . The $R_{DS(on)}$ at 70 °C can be extrapolated from this data using the following formula

 $R_{DS(on)}$ (at 70 °C) = $R_{DS(on)}$ (at 25 °C) x (1 + $T_C x \Delta T$)

Where T_C is 3300 ppm/°C. Continuing with the calculation we have

 $R_{DS(on)}$ (at 70 °C) = 480 mΩ x (1 + 0.0033 x (70 °C - 25 °C)) = 551 mΩ

The maximum current limit is then determined by

$$I_{LOAD}$$
 (max.) < $\sqrt{\frac{P (max.)}{R_{DS(on)}}}$

which in case is 1.05 A. Under the stated input voltage condition, if the 1.05 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

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PRODUCT SUMMARY				
Part number	SiP4282	SiP4282	SiP4282A	SiP4282A
Description	$\begin{array}{c} \text{1.8 V to 5.5 V, 105 m}\Omega,\\ \text{100 } \mu\text{s rise time, with}\\ \text{UVLO} \end{array}$	$\begin{array}{c} \text{1.8 V to 5.5 V, 105 m}\Omega,\\ \text{100 } \mu\text{s rise time, with}\\ \text{UVLO} \end{array}$	1.5 V to 5.5 V, 105 mΩ, 100 μs rise time	1.5 V to 5.5 V, 105 mΩ, 100 μs rise time
Configuration	Single	Single	Single	Single
Slew rate time (µs)	140	140	140	140
On delay time (μs)	20	20	20	20
Input voltage min. (V)	1.8	1.8	1.5	1.5
Input voltage max. (V)	5.5	5.5	5.5	5.5
On-resistance at input voltage min. (m Ω)	230	230	350	350
On-resistance at input voltage max. (m Ω)	105	105	105	105
Quiescent current at input voltage min. (µA)	1	1	0.00001	0.00001
Quiescent current at input voltage max. (µA)	2.5	2.5	0.00005	0.00005
Output discharge (yes / no)	Yes	Yes	Yes	Yes
Reverse blocking (yes / no)	No	No	No	No
Continuous current (A)	1.2	1.2	1.2	1.2
Package type	TDFN4	PowerPAK SC-75-6	TDFN4	PowerPAK SC-75-6
Package size (W, L, H) (mm)	1.2 x 1.6 x 0.5	0.75 x 1.6 x 0.5	1.2 x 1.6 x 0.5	0.75 x 1.6 x 0.5
Status code	2	2	2	2
Product type	Slew rate	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

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TDFN4 1.2 x 1.6 Case Outline



Top View



Bottom View



Side View

DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A	0.45	0.55	0.60	0.017	0.022	0.024	
A1	0.00	-	0.05	0.00	-	0.002	
A3	0.1	5 REF. or 0.127 REF	(1)		0.006 or 0.005 ⁽¹⁾		
b	0.20	0.25	0.30	0.008	0.010	0.012	
D	1.15	1.20	1.25	0.045	0.047	0.049	
D2	0.81	0.86	0.91	0.032	0.034	0.036	
e		0.50 BSC			0.020		
E	1.55	1.60	1.65	0.061	0.063	0.065	
E2	0.45	0.50	0.55	0.018	0.020	0.022	
К	0.25 typ. 0.010 typ.						
L	0.25	0.30	0.35	0.010	0.012	0.014	
ECN: T16-0143-Rev. C, 18-Apr-16 DWG: 5995							

Note

⁽¹⁾ The dimension depends on the leadframe that assembly house used.

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PowerPAK[®] SC75-6L (Power IC only)





		MILLIMETERS	6	INCHES				
DIM	Min	Nom	Max	Min	Nom	Max		
A	0.70	0.75	0.80	0.028	0.030	0.032		
A1	0	-	0.05	0	-	0.002		
b	0.20	0.25	0.30	0.008	0.010	0.012		
С	0.15	0.20	0.25	0.006	0.008	0.010		
D	1.55	1.60	1.65	0.0061	0.063	0.065		
D1	0.95	1.00	1.05	0.037	0.039	0.041		
E	1.55	1.60	1.65	0.061	0.063	0.065		
E1	0.55	0.60	0.65	0.022	0.024	0.026		
е	0.50 BSC 0.020 BSC							
e1		1.00 BSC			0.039 BSC			
К	0.15	-	-	0.006	-	-		
K2	0.20	-	-	0.008				
L	0.20	0.25	0.30	0.008	0.010	0.012		
ECN: S-60845-Rev. B, 22-May-06 DWG: 5953								



RECOMMENDED MINIMUM PADS FOR TDFN4 1.2 x 1.6



Recommended Minimum Pads Dimensions in mm



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